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N-Channel Enhancement Mode Field Effect Transistor

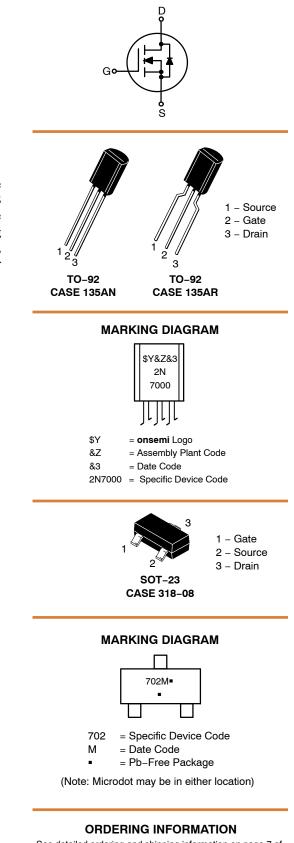
2N7000, 2N7002, NDS7002A

Description

These N-channel enhancement mode field effect transistors are produced using **onsemi**'s proprietary, high cell density, DMOS technology. These products have been designed to minimize on-state resistance while providing rugged, reliable, and fast switching performance. These products are particularly suited for low-voltage, low-current applications, such as small servo motor control, power MOSFET gate drivers, and other switching applications.

Features

- High Density Cell Design for Low RDS(on)
- Voltage Controlled Small Signal Switch
- Rugged and Reliable
- High Saturation Current Capability
- ESD Protection Level: HBM > 100 V, CDM > 2 kV
- This Device is Pb-Free and Halogen Free



See detailed ordering and shipping information on page 7 of this data sheet.

			Value		
Symbol	Parameter	2N7000	2N7002	NDS7002A	Unit
V _{DSS}	Drain-to-Source Voltage		60	•	V
V _{DGR}	Drain-Gate Voltage ($R_{GS} \le 1$ MW)		60		V
V _{GSS}	Gate-Source Voltage - Continuous		±20		V
	Gate-Source Voltage - Non Repetitive (tp < 50 ms)		±40		
Ι _D	Maximum Drain Current – Continuous	200	115	280	mA
	Maximum Drain Current – Pulsed	500	800	1500	
PD	Maximum Power Dissipation Derated above 25°C	400	200	300	mW
		3.2	1.6	2.4	mW/°C
T _J , T _{STG}	Operating and Storage Temperature Range	-55	to 150	-65 to 150	°C
ΤL	Maximum Lead Temperature for Soldering Purposes, 1/16-inch from Case for 10 s		300		°C

ABSOLUTE MAXIMUM RATINGS Values are at $T_C = 25^{\circ}C$ unless otherwise noted.

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS Values are at $T_C = 25^{\circ}C$ unless otherwise noted.

			Value		
Symbol	Parameter	2N7000	2N7002	NDS7002A	Unit
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	312.5	625	417	°C/W

ELECTRICAL CHARACTERISTICS

Values are at T_C = 25°C unless otherwise noted.

Symbol	Parameter	Conditions	Туре	Min	Тур	Max	Unit
OFF CHARA	CTERISTICS						
BV _{DSS}	Drain-Source Breakdown Voltage	V_{GS} = 0 V, I _D = 10 μ A	All	60	_	_	V
I _{DSS}	Zero Gate Voltage Drain	$V_{DS} = 48 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	2N7000	-	-	1	μA
	Current	$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}, T_{C} = 125^{\circ}\text{C}$		-	-	1	mA
		$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$	2N7002	_	-	1	μA
		V_{DS} = 60 V, V_{GS} = 0 V, T _C = 125°C	NDS7002A	-	-	0.5	mA
I _{GSSF}	Gate – Body Leakage,	V_{GS} = 15 V, V_{DS} = 0 V	2N7000	-	-	10	nA
	Forward	V_{GS} = 20 V, V_{DS} = 0 V	2N7002 NDS7002A	-	_	100	
I _{GSSR}	Gate – Body Leakage,	$V_{GS} = -15 \text{ V}, V_{DS} = 0 \text{ V}$	2N7000	_	-	-10	nA
	Reverse	V_{GS} = -20 V, V_{DS} = 0 V	2N7002 NDS7002A	-	-	-100	1

ON CHARACTERISTICS

V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 1 \text{ mA}$	2N7000	0.8	2.1	3	V
		$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	2N7002 NDS7002A	1	2.1	2.5	

ELECTRICAL CHARACTERISTICS (continued) Values are at $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Conditions	Туре	Min	Тур	Max	Unit
ON CHARAC	TERISTICS						
R _{DS(on)}	Static Drain-Source	V_{GS} = 10 V, I _D = 500 mA	2N7000	-	1.2	5	Ω
	On-Resistance	V_{GS} = 10 V, I _D = 500 mA, T _C = 125°C		-	1.9	9	
		V _{GS} = 4.5 V, I _D = 75 mA		-	1.8	5.3	
		V_{GS} = 10 V, I _D = 500 mA	2N7002	-	1.2	7.5	
		$\label{eq:VGS} \begin{array}{l} V_{GS} = 10 \text{ V}, \text{ I}_{D} = 500 \text{ mA}, \\ T_{C} = 100^{\circ}\text{C} \end{array}$		-	1.7	13.5	
		$V_{GS} = 5 \text{ V}, \text{ I}_{D} = 50 \text{ mA}$		- 1.7	7.5	1	
		V_{GS} = 5 V, I _D = 50 mA, T _C = 100°C		-	2.4	13.5	
		V_{GS} = 10 V, I _D = 500 mA	NDS7002A	-	1.2	2	
		V_{GS} = 10 V, I_{D} = 500 mA, T_{C} = 125°C		-	2	3.5	
		V_{GS} = 5 V, I_D = 50 mA		-	1.7	3	
		V_{GS} = 5 V, I_D = 50 mA, T_C = 125°C		-	2.8	5	
V _{DS(on)}	Drain-Source On-Voltage	V _{GS} = 10 V, I _D = 500 mA	2N7000	-	0.6	2.5	V
		V_{GS} = 4.5 V, I _D = 75 mA		-	0.14	0.4	
		V_{GS} = 10 V, I _D = 500 mA	2N7002	-	0.6	3.75	
		$V_{GS} = 5.0 \text{ V}, \text{ I}_{D} = 50 \text{ mA}$		-	0.09	1.5	
		V_{GS} = 10 V, I _D = 500 mA	NDS7002A	-	0.6	1	
		$V_{GS} = 5.0 \text{ V}, \text{ I}_{D} = 50 \text{ mA}$		-	0.09	0.15	
g fs	Forward Transconductance	V_{DS} = 10 V, I _D = 200 mA	2N7000	100	320	-	mS
		$V_{DS} \geq 2 \ V_{DS(on)}, \ I_D = 200 \ mA$	2N7002	80	320	-]
		$V_{DS} \ge 2 V_{DS(on)}, I_D = 200 \text{ mA}$	NDS7002A	80	320	-]

DYNAMIC CHARACTERISTICS

C _{iss}	Input Capacitance	$V_{DS} = 25 V, V_{GS} = 0 V,$	All	-	20	50	pF
Coss	Output Capacitance	f = 1.0 MHz	All	-	11	25	
C _{rss}	Reverse Transfer Capacitance		All	_	4	5	
t _{on}	Turn-On Time		2N7000	-	-	10	ns
			2N7002 NDS7002A	-	-	20	
t _{off}	Turn-Off Time		2N7000	-	-	10	ns
			2N7002 NDS7002A	-	-	20	
AIN-SO	URCE DIODE CHARACTERIS	TICS AND MAXIMUM RATINGS					-
ا _S	Maximum Continuous Drair	n-Source Diode Forward Current	2N7002	_	-	115	mA

۱ _S	Maximum Continuous Drain-Source Diode Forward Current	2N7002	-	-	115	mA
		NDS7002A	-	-	280	

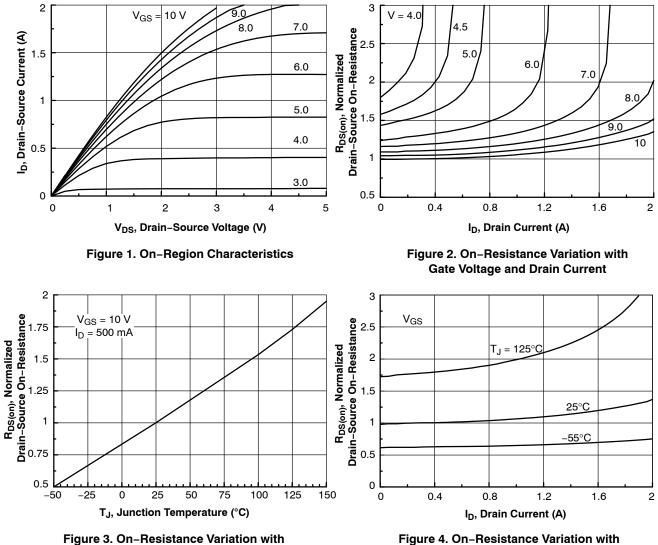
ELECTRICAL CHARACTERISTICS (continued)

Values are at $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Conditions	Туре	Min	Тур	Max	Unit
DRAIN-SOU	RCE DIODE CHARACTERISTICS	AND MAXIMUM RATINGS					
I _{SM}	Maximum Pulsed Drain-Source	Diode Forward Current	2N7002	-	_	0.8	А
			NDS7002A	-	-	1.5	
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = 115 mA (Note 1)	2N7002	-	0.88	1.5	V
		V_{GS} = 0 V, I _S = 400 mA (Note 1)	NDS7002A	_	0.88	1.2	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse test: Pulse Width \leq 300 $\mu s,$ Duty Cycel \leq 2 %

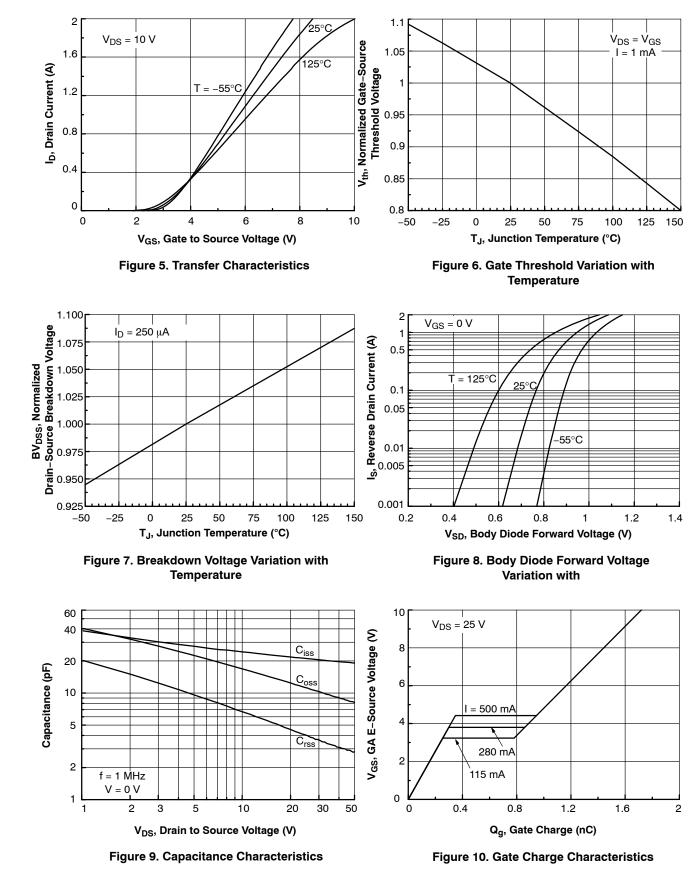


TYPICAL PERFORMANCE CHARACTERISTICS

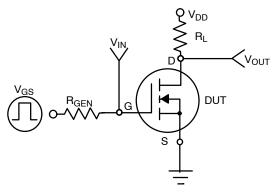
Temperature

Figure 4. On–Resistance Variation with Drain Current and Temperature





TYPICAL PERFORMANCE CHARACTERISTICS (CONTINUED)





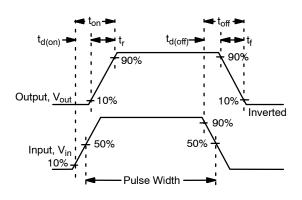


Figure 12. Switching Waveforms

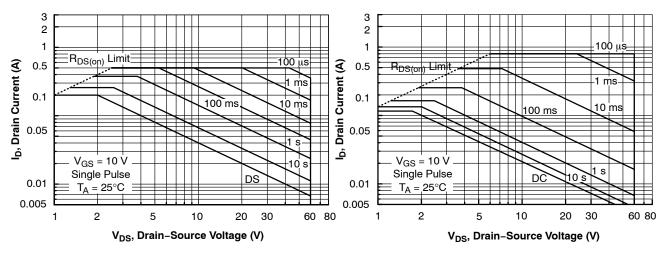




Figure 14. 2N7002 Maximum Safe Operating Area

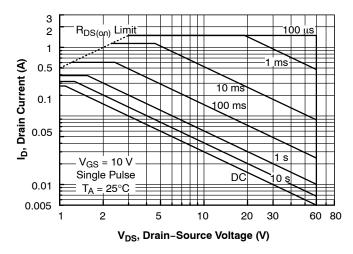


Figure 15. NDS7000A Maximum Safe Operating Area

TYPICAL PERFORMANCE CHARACTERISTICS (CONTINUED)

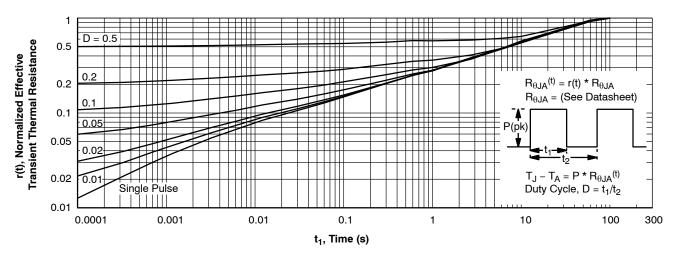


Figure 16. TO-92, 2N7000 Transient Thermal Response Curve

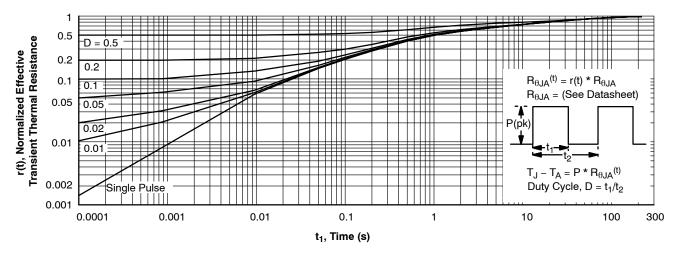


Figure 17. SOT-23, 2N7002 / NDS7002A Transient Thermal Response Curve

ORDERING INFORMATION

Part Number	Marking	Package	Packing Method †	Min Order Qty / Immediate Pack Qty
2N7000	2N7000	TO-92 3L	Bulk	10000 / 1000
2N7000-D74Z		(Pb-Free)	Ammo	2000 / 2000
2N7000-D75Z			Tape and Reel	2000 / 2000
2N7000-D26Z				2000 / 2000
2N7002	702	SOT-23 3L	Tape and Reel	3000 / 3000
NDS7002A	712	(Pb-Free)		3000 / 3000

⁺For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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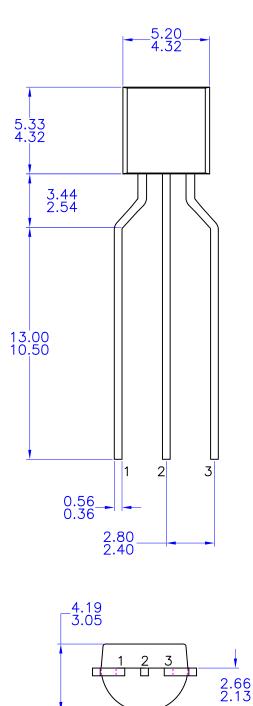
TO-92 3 4.825x4.76 CASE 135AN ISSUE O DATE 31 JUL 2016 _5.20_ ______ 5.33 (0.81) 15.62 2 3 1 0.52 0.56 0.36 1.27 NOTES: UNLESS OTHERWISE SPECIFIED 2.54 A) DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS. B) ALL DIMENSIONS ARE IN MILLIMETERS. с́э DRAWING CONFORMS TO ASME Y14.5M-2009. 4.19 3.05 2.66 2.13 2 3 1 Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. **DOCUMENT NUMBER:** 98AON13880G **DESCRIPTION:** TO-92 3 4.825X4.76 PAGE 1 OF 1

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SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318**

ISSUE AU

DATE 14 AUG 2024









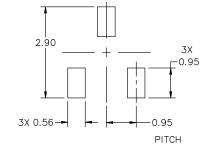




XXX = Specific Device Code М = Date Code

= Pb-Free Package .

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



MILLIMETERS							
DIM	MIN	NOM	МАХ				
А	0.89	1.00	1.11				
A1	0.01	0.06	0.10				
b	0.37	0.44	0.50				
с	0.08	0.14	0.20				
D	2.80	2.90	3.04				
E	1.20	1.30	1.40				
е	1.78	1.90	2.04				
L	0.30	0.43	0.55				
L1	0.35	0.54	0.69				
Ηe	2.10	2.40	2.64				
Т	0°		10°				

NOTES:

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: 1.

2. MILLIMETERS.

MILLIME IERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE 3.

BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS, OR GATE BURRS.

RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	ı	
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	I PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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